ABSOLUTE MAXIMUM RATINGS

Voltages Referenced to GND	
V+	0.3V to +17V
V	+0.3V to -17V
V+ to V	0.3V to +17V
Voltage into Any Terminal (Note	1)($V2V$) to ($V++2V$)
or	30mA (whichever occurs first)
Continuous Current into Any Term	ninal±30mÅ
Peak Current, NO or COM	
(pulsed at 1ms, 10% duty cycle))±100mA
"	

Continuous Power Dissipation ($T_A = +70^{\circ}C$)	
Plastic DIP (derate 10.53mW/°C above +70°C)	842mW
Narrow SO (derate 8.70mW/°C above +70°C)	
QSOP (derate 8.00mW/°C above +70°C)	640mW
CERDIP (derate 10.00mW/°C above +70°C)	800mW
Operating Temperature Ranges	
MAX405_C_ E/MAX405_AC_E	0°C to +70°C
MAX405_E_ E/MAX405_AE_E	-40°C to +85°C
MAX405_MJE/MAX405_AMJE5	55°C to +125°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C

Note 1: Signals on any terminal exceeding V+ or V- are clamped by internal diodes. Limit forward-diode current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—Dual Supplies

 $(V+ = +4.5V \text{ to } +5.5V, V- = -4.5V \text{ to } -5.5V, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted.}$ Typical values are at $T_A = +25^{\circ}C.$)

PARAMETER	SYMBOL	CONDITIONS			MIN	TYP (Note 2)	MAX	UNITS
ANALOG SWITCH								
Analog Signal Range	V _{COM} , V _{NO}			C, E, M	V-		V+	V
COM-NO On-Resistance	Ron	V+ = 5V, V- = -5V, I _{NO} =	1mA,	T _A = +25°C		60	100	Ω
OCIVI IVO OII FICOISIAI IOC	11011	V _{COM} = ±3V		C, E, M			125	
			MAX4051A, MAX4052A.	T _A = +25°C			6	
COM-NO On-Resistance Match Between Channels (Note 3) $ \begin{array}{c} V+=5V,\ V-=-5V, \\ I_{NO}=1\text{mA}, \\ V_{COM}=\pm 3V \end{array} $ MAX4053A MAX4051,	C, E, M			12	Ω			
	211014		MAX4051, MAX4052.	T _A = +25°C			12	
		MAX4053		C, E, M			18	
COM-NO On-Resistance	DEL ATIONS	V+ = 5V, V- = -5V, INO = 1mA,	MAX4051A, MAX4052A.	T _A = +25°C			10	Ω
Flatness (Note 4)	Rflat(on)	VCOM = -3V, 0V, 3V	MAX4053A	C, E, M			15	3 52
		V+ = 5.5V, V- = -5.5V,	MAX4051,	T _A = +25°C	-1	0.002	1	
		$V_{NO} = 4.5V,$	MAX4052,	C, E	-10		10	
NO Off-Leakage Current (Note 5)	INO(OFF)	$V_{COM} = -4.5V$	MAX4053	М	-100	<u> </u>	100	nA
	I _{NO(OFF)}	V+ = 5.5V, V- = -5.5V,	MAX4051A, MAX4052A,	T _A = +25°C	-0.1	0.002	0.1] ''^
		$V_{NO} = -4.5V$, MAX4052A, C		C, E	-5		5	
			М	-100		100	1	

ELECTRICAL CHARACTERISTICS—Dual Supplies (continued)

 $(V+ = +4.5V \text{ to } +5.5V, V- = -4.5V \text{ to } -5.5V, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted.}$ Typical values are at $T_A = +25^{\circ}C.)$

PARAMETER	SYMBOL	CONI	DITIONS		MIN	TYP (Note 2)	MAX	UNITS
				$T_A = +25^{\circ}C$	-0.1	0.002	0.1	
			MAX4051A	C, E	-5		5	1
				М	-100		100	
				$T_A = +25^{\circ}C$	-1	0.002	1	
			MAX4051	C, E	-10		10	
		V+ = 5.5V, V- = -5.5V, $V_{NO} = 4.5V,$		М	-100		100	
		$V_{NO} = 4.5V$, $V_{COM} = -4.5V$	NAAWA050A	$T_A = +25^{\circ}C$	-0.1	0.002	0.1	1
		TOOM!	MAX4052A, MAX4053A	C, E	-2.5		2.5	
			1017 01403071	М	-100		100	1
			NAAWA050	T _A = +25°C	-1	0.002	1	
			MAX4052, MAX4053	C, E	-5		5	
COM Off-Leakage	loov (OFF)		1017 014000	М	-50		50	nA
Current (Note 5)	ICOM(OFF)			$T_A = +25^{\circ}C$	-0.1	0.002	0.1] 11/4
			MAX4051A	C, E	-5		5	
				М	-100		100	
				$T_A = +25^{\circ}C$	-1	0.002	1	
			MAX4051	C, E	-10		10	
		V+ = 5.5V, V- = -5.5V, V _{NO} = -4.5V, V _{COM} = 4.5V		М	-100		100	
			MAX4052A, MAX4053A	$T_A = +25^{\circ}C$	-0.1	0.002	0.1	
				C, E	-2.5		2.5	
				М	-50		50	
			MAX4052, MAX4053	$T_A = +25^{\circ}C$	-1	0.002	1	
				C, E	-5		5	
			1000	М	-50		50	
				$T_A = +25^{\circ}C$	-0.1	0.002	0.1	
			MAX4051A	C, E	-5		5	
				М	-100		100	
				$T_A = +25^{\circ}C$	-1	0.002	1	
			MAX4051	C, E	-10		10	
COM On-Leakage	ICOM(ON)	V+ = 5.5V, V- = -5.5V,		М	-100		100	nA
Current (Note 5)	ICONI(ON)	$V_{COM} = V_{NO} = \pm 4.5V$	MAX4052A,	T _A = +25°C	-0.1	0.002	0.1	
			MAX4052A,	C, E	-2.5		2.5	
				М	-50		50	
			MAX4052, MAX4053	T _A = +25°C	-1	0.002	1	
		MAX4052, - MAX4053		C, E	-5		5	
			М	-50		50		

ELECTRICAL CHARACTERISTICS—Dual Supplies (continued)

 $(V + = +4.5V \text{ to } +5.5V, V - = -4.5V \text{ to } -5.5V, T_A = T_{MIN} \text{ to } T_{MAX}, \text{ unless otherwise noted.}$ Typical values are at $T_A = +25^{\circ}C.)$

PARAMETER	SYMBOL	CONDITIONS		MIN	TYP (Note 2	MAX)	UNITS	
DIGITAL I/O							I	
ADD, INH Input Logic Threshold High	VIH		C, E, M	2.4			V	
ADD, INH Input Logic Threshold Low	VIL		C, E, M			0.8	V	
ADD, INH Input Current Logic High or Low	I _{IH} , I _{IL}	V _{ADD} , V _{INH} = V+, 0V	C, E, M	-1	0.03	1	μА	
SWITCH DYNAMIC CHA	RACTERISTIC	S					•	
Turn-On Time (Note 6)	ton	Figure 3	T _A = +25°C		50	175	ns ns	
rain on time (Note o)	ίΟΝ.	Figure 3	C, E, M			225	110	
Turn-Off Time (Note 6)	toff	L Figure 3	$T_A = +25$ °C		40	150	- ns	
rum-on mine (Note o)	UFF	rigure 3	C, E, M			200		
Transition Time	ttrans	Figure 2	T _A = +25°C		75	250	ns	
Break-Before-Make Delay	topen	Figure 4	T _A = +25°C	2	10		ns	
Charge Injection (Note 6)	Q	$C_L = 1$ nF, $R_S = 0$ Ω , $V_{NO} = 0$ V, Figure 5	T _A = +25°C		2	10	рС	
NO Off-Capacitance	C _{NO} (OFF)	V _{NO} = GND, f = 1MHz, Figure 7	T _A = +25°C		2		pF	
COM Off-Capacitance	CCOM(OFF)	VCOM = GND, f = 1MHz, Figure 7	T _A = +25°C		2		рF	
Switch On-Capacitance	C(ON)	V _{COM} = V _{NO} = GND, f = 1MHz, Figure 7	T _A = +25°C		8		pF	
Off-Isolation	VISO	$C_L = 15 pF$, $R_L = 50 \Omega$, $f = 100 kHz$, $V_{NO} = 1 V_{RMS}$, Figure 6	T _A = +25°C		<-90		dB	
Channel-to-Channel Crosstalk	V _C T	$C_L = 15 pF$, $R_L = 50\Omega$, $f = 100 kHz$, $V_{NO} = 1 V_{RMS}$, Figure 6	T _A = +25°C		<-90		dB	
POWER SUPPLY							1	
Power-Supply Range	V+, V-		C, E, M	±2.7		±8	V	
V+ Supply Current	l+	INH = ADD = 0V or V+	T _A = +25°C	-1	0.1	1	μΑ	
v + Supply Culterit	I+	IND = ADD = UV OF V+	C, E, M			10	_ μA	
V- Supply Current	-	INH = ADD = 0V or V+	$T_A = +25^{\circ}C$	-1	0.1	1	T	
v- Juppiy Guiterit	I-		C, E, M	-10			μΑ	

- Note 2: The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.
- **Note 3:** $\Delta R_{ON} = R_{ON(MAX)} R_{ON(MIN)}$.
- **Note 4:** Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges; i.e., V_{NO} = 3V to 0V and 0V to -3V.
- Note 5: Leakage parameters are 100% tested at maximum-rated hot operating temperature, and guaranteed by correlation at $T_A = +25^{\circ}C$.
- Note 6: Guaranteed by design, not production tested.

ELECTRICAL CHARACTERISTICS—Single +5V Supply

(V+ = +4.5V to +5.5V, V- = 0V, TA = TMIN to TMAX, unless otherwise noted. Typical values are at $TA = +25^{\circ}C.)$

PARAMETER	SYMBOL	CONE	DITIONS		MIN	TYP (Note 2)	MAX	UNITS
ANALOG SWITCH								
Analog Signal Range	VCOM, VNO			C, E, M	V-		V+	V
COM-NO On-Resistance	Ron	$V+ = 5V$, $I_{NO} = 1mA$,	$V+ = 5V, I_{NO} = 1mA,$			125	225	Ω
COM-NO OH-NESISIANCE	HON	$V_{COM} = 3.5V$		C, E, M			280	32
		V 5 5 V V 2 4 5 V		$T_A = +25^{\circ}C$	-1	0.002	1	
		$V + = 5.5V, V_{NO} = 4.5V, V_{COM} = 0V$		C, E	-10		10	
NO Off-Leakage Current	INO(OFF)	100W 11		М	-100		100	nA
(Note 5)	INO(OFF)	$V+ = 5.5V, V_{NO} = 0V,$		$T_A = +25^{\circ}C$	-1	0.002	1] ""
		$V + = 5.5V$, $V_{NO} = 0V$, $V_{COM} = 4.5V$		C, E	-10		10	
		100W	_	M	-100		100]
				$T_A = +25^{\circ}C$	-1	0.002	1	
		V+ = 5.5V, V _{NO} = 4.5V, V _{COM} = 0V	MAX4051/A	C, E	-10		10	
				М	-100		100	nA
COM Off-Leakage	ICOM(OFF)		MAX4052/A,	$T_A = +25^{\circ}C$	-1	0.002	1	
			MAX4052/A,	C, E	-5		5	
			5 (1000)	М	-50		50	
Current (Note 5)	ICOM(OFF)			$T_A = +25^{\circ}C$	-1	0.002	1	
			MAX4051/A	C, E	-10		10	
		$V + = 5.5V$, $V_{NO} = 0V$, $V_{COM} = 4.5V$ or $0V$		М	-100		100	
			NAAV40E0/A	$T_A = +25^{\circ}C$	-1	0.002	1	
			MAX4052/A, - MAX4053/A	C, E	-5		5	
			5 (1000)	М	-50		50	
				$T_A = +25^{\circ}C$	-1	0.002	1	
			MAX4051/A	C, E	-10		10	1
COM On-Leakage	ICOM(ON)	V+ = 5.5V,		M	-100		100	nA
Current (Note 5)	ICOM(ON)	$V_{COM} = V_{NO} = 4.5V$	MAX4052/A,	$T_A = +25^{\circ}C$	-1	0.002	1	
			MAX4052/A,	C, E	-10		10	
			5 (1000)	М	-100		100	
DIGITAL I/O								
ADD, INH Input Logic Threshold High	VIH			C, E, M	2.4			V
ADD, INH Input Logic Threshold Low	VIL			C, E, M			0.8	V
ADD, INH Input Current Logic High or Low	lih, lil	VADD, VINH = V+, 0V		C, E, M	-1	0.03	1	μΑ
POWER SUPPLY		I		1				1
	1.	INILL ADD OVV		T _A = +25°C	-1		1	
V+ Supply Current	I+	INH = ADD = 0V or V+		C, E, M			10	μΑ



ELECTRICAL CHARACTERISTICS—Single +5V Supply (continued)

(V+ = +4.5V to +5.5V, V- = 0V, TA = TMIN to TMAX, unless otherwise noted. Typical values are at $TA = +25^{\circ}C.)$

PARAMETER	SYMBOL	CONDITIONS			TYP (Note 2)	MAX	UNITS	
SWITCH DYNAMIC CHA	RACTERISTIC	S						
Turn On Time (Note 6)	+	Figure 2	$T_A = +25^{\circ}C$		90	200	200	
Turn-On Time (Note 6)	ton	Figure 3	C, E, M			275	ns	
Turn Off Time (Note 6)	torr	Figure 3	$T_A = +25^{\circ}C$		60	125	ns	
Turn-Off Time (Note 6)	tOFF	Figure 5	C, E, M			175	7 113	
Break-Before-Make Delay	topen	Figure 4	$T_A = +25^{\circ}C$		30		ns	
Charge Injection (Note 6)	Q	$C_L = 1$ nF, $R_S = 0$ Ω , $V_{NO} = 0$ V, Figure 5	T _A = +25°C		2	10	рС	
Off-Isolation	V _{ISO}	$C_L = 15 pF$, $R_L = 50 \Omega$, $f = 100 kHz$, $V_{NO} = 1 V_{RMS}$, Figure 6	T _A = +25°C		<-90		dB	
Channel-to-Channel Crosstalk	V _{CT}	$C_L = 15 pF$, $R_L = 50 \Omega$, $f = 100 kHz$, $V_{NO} = 1 V_{RMS}$, Figure 6	T _A = +25°C		<-90		dB	

- Note 2: The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.
- Note 3: $\Delta R_{ON} = R_{ON(MAX)} R_{ON(MIN)}$.
- **Note 4:** Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges; i.e., V_{NO} = 3V to 0V and 0V to -3V.
- Note 5: Leakage parameters are 100% tested at maximum-rated hot operating temperature, and guaranteed by correlation at $T_A = +25^{\circ}C$.
- Note 6: Guaranteed by design, not production tested.

ELECTRICAL CHARACTERISTICS—Single +3V Supply

(V+ = +3.0V to +3.6V, V- = 0V, TA = TMIN to TMAX, unless otherwise noted. Typical values are at $TA = +25^{\circ}C.)$

PARAMETER	SYMBOL	CONI	DITIONS		MIN	TYP (Note 2)	MAX	UNITS
ANALOG SWITCH								1
Analog Signal Range	V _{COM} , V _{NO}			C, E, M	V-		V+	V
COM-NO On-Resistance	Ron	$I_{NO} = 1 \text{mA}, V_{+} = 3V,$		T _A = +25°C		250	525	Ω
COM-NO On-nesistance	HON	V _{COM} = 1.5V		C, E, M			700] 52
		V 0 0 V V 0 0 V		T _A = +25°C	-1	0.002	1	
NO Off-Leakage Current		$V + = 3.6V, V_{NO} = 3V, V_{COM} = 0V$		C, E	-10		10	
	INO(OFF)	- COM		М	-100		100	nA
(Note 5)	I _{NO(OFF)}	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\		$T_A = +25^{\circ}C$	٦-	0.002	1	
		$V + = 3.6V, V_{NO} = 0V, V_{COM} = 3V$		C, E	-10		10	
		- COM		М	-100		100	
				$T_A = +25^{\circ}C$	-1	0.002	1	
		V+ = 3.6V, V _{NO} = 3V, V _{COM} = 0V	MAX4051/A	C, E	-10		10	
				М	-100		100	
			MAX4052/A,	$T_A = +25^{\circ}C$	-1	0.002	1	nA
			MAX4052/A,	C, E	-5		5	
COM Off-Leakage	ICOM(OFF)		·	М	-50		50	
Current (Note 5)	ICOM(OFF)			$T_A = +25^{\circ}C$	-1	0.002	1	
			MAX4051/A	C, E	-10		10	
		$V+ = 3.6V, V_{NO} = 0V,$		М	-100		100	
		V _{COM} = 3V	MAX4052/A, MAX4053/A	$T_A = +25^{\circ}C$	-1	0.002	1	
				C, E	-5		5	
			·	М	-50		50	
				$T_A = +25^{\circ}C$	-1	0.002	1	
			MAX4051/A	C, E	-10		10	
COM On-Leakage	ICOM(ON)	V+ = 3.6V,		М	-100		100	nA
Current (Note 5)	100101(014)	$V_{COM} = V_{NO} = 3V$	MAX4052/A,	$T_A = +25^{\circ}C$	-1	0.002	1	
			MAX4053/A	C, E	-10		10	
				M	-100		100	
DIGITAL I/O		T						T
ADD, INH Input Logic Threshold High	VIH			C, E, M	2.4			V
ADD, INH Input Logic Threshold Low	VIL			C, E, M			0.8	V
ADD, INH Input Current Logic High or Low	I _{IH,} I _{IL}	V _{ADD} , V _{INH} = V+, 0V		C, E, M	-1	0.03	1	μΑ
POWER SUPPLY		1		I	1			ı
V. Cumply Comment	1 -	INILL ADD OVV		T _A = +25°C	-1		1	
V+ Supply Current	l+	INH = ADD = UV or V+	INH = ADD = 0V or V+				10	- μA



ELECTRICAL CHARACTERISTICS—Single +3V Supply (continued)

(V+ = +3.0V to +3.6V, V- = 0V, TA = TMIN to TMAX, unless otherwise noted. Typical values are at $TA = +25^{\circ}C.)$

PARAMETER	SYMBOL	CONDITIONS	MIN TYP (Note	MAX 2)	UNITS		
SWITCH DYNAMIC CHA	RACTERISTIC	S				•	
Turn On Time (Note 6)	ton	Eiguro 2	$T_A = +25^{\circ}C$	180	600	200	
Turn-On Time (Note 6)	ton	Figure 3	C, E, M		700	ns	
Turn Off Time (Note 6)	torr	Figure 2	$T_A = +25^{\circ}C$	100	300	ns	
Turn-Off Time (Note 6)	toff	Figure 3	C, E, M		400	7 115	
Break-Before-Make Delay	topen	Figure 4	$T_A = +25^{\circ}C$	90		ns	
Charge Injection (Note 6)	Q	$C_L = 1 n F, R_S = 0 \Omega, V_{NO} = 0 V,$ Figure 5	T _A = +25°C	1	10	рС	
Off-Isolation	V _{ISO}	$C_L = 15 pF$, $R_L = 50 \Omega$, $f = 100 kHz$, $V_{NO} = 1 V_{RMS}$, Figure 6	T _A = +25°C	<-90		dB	
Channel-to-Channel Crosstalk	V _{CT}	$C_L = 15 pF$, $R_L = 50 \Omega$, $f = 100 kHz$, $V_{NO} = 1 V_{RMS}$, Figure 6	T _A = +25°C	<-90		dB	

Note 2: The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.

Note 3: $\Delta R_{ON} = R_{ON(MAX)} - R_{ON(MIN)}$.

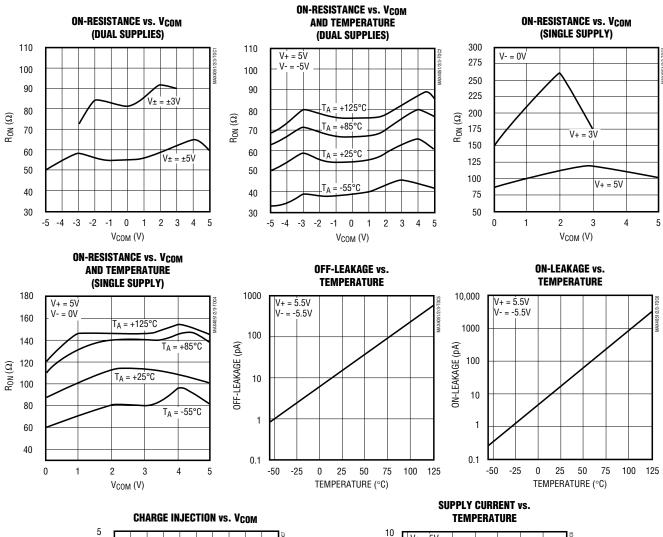
Note 4: Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges; i.e., V_{NO} = 3V to 0V and 0V to -3V.

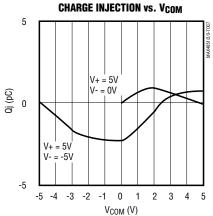
Note 5: Leakage parameters are 100% tested at maximum-rated hot operating temperature, and guaranteed by correlation at $T_A = +25^{\circ}C$.

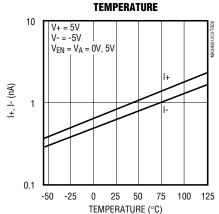
Note 6: Guaranteed by design, not production tested.

Typical Operating Characteristics

 $(V+=+5V, V-=-5V, GND=0V, T_A=+25^{\circ}C, unless otherwise noted.)$



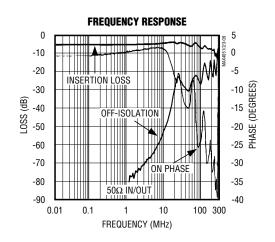


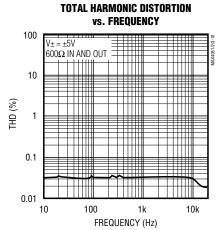


MIXIM

Typical Operating Characteristics (continued)

 $(V+ = +5V, V- = -5V, GND = 0V, T_A = +25^{\circ}C, unless otherwise noted.)$





_Pin Descriptions

	PIN			
MAX4051/ MAX4051A	MAX4052/ MAX4052A	MAX4053/ MAX4053A	NAME	FUNCTION
1, 2, 4, 5, 12, 13, 14, 15	_	_	NO0-NO7	Analog Switch Inputs 0-7
3	_	_	COM	Analog Switch Common
_	1, 2, 4, 5	_	NO0B-NO3B	Analog Switch "B" Inputs 0–3
_	3	15	COMB	Analog Switch "B" Common
_	_	1	NOB	Analog Switch "B" Normally Open Input
_	_	2	NCB	Analog Switch "B" Normally Closed Input
_	_	3	NOA	Analog Switch "A" Normally Open Input
_	_	5	NCA	Analog Switch "A" Normally Closed Input
6	6	6	INH	Digital Inhibit Input. Normally connect to GND. Can be driven to logic high to set all switches off.
7	7	7	V-	Negative Analog Supply Voltage Input. Connect to GND for single-supply operation.
8	8	8	GND	Ground. Connect to digital ground. (Analog signals have no ground reference; they are limited to V+ and V)
9	_	11	ADDC	Digital Address "C" Input
10	9	10	ADDB	Digital Address "B" Input
11	10	9	ADDA	Digital Address "A" Input
_	11, 12, 14, 15	_	NO0A-NO3A	Analog Switch "A" Inputs 0-3
_	13	4	COMA	Analog Switch "A" Common
_	_	12	NCC	Analog Switch "C" Normally Closed Input
_	_	13	NOC	Analog Switch "C" Normally Open Input
_	_	14	COMC	Analog Switch "C" Common
16	16	16	V+	Positive Analog and Digital Supply Voltage Input

Note: NO, NC, and COM pins are identical and interchangeable. Any may be considered an input or output; signals pass equally well in both directions.

Table 1. Truth Table/Switch Programming

	А	DDRESS BIT	S		ON SWITCHES	
INH	ADDC*	ADDB	ADDA	MAX4051/ MAX4051A	MAX4052/ MAX4052A	MAX4053/ MAX4053A
1	Х	Х	Х	All switches open	All switches open	All switches open
0	0	0	0	COM-NO0	COMB-NO0B, COMA-NO0A	COMA-NCA, COMB-NCB, COMC-NCC
0	0	0	1	COM-NO1	COMB-NO1B, COMA-NO1A	COMA-NOA, COMB-NCB, COMC-NCC
0	0	1	0	COM-NO2	COMB-NO2B, COMA-NO2A	COMA-NCA, COMB-NOB, COMC-NCC
0	0	1	1	COM-NO3	COMB-NO3B, COMA-NO3A	COMA-NOA, COMB-NOB, COMC-NCC
0	1	0	0	COM-NO4	COMB-NO0B, COMA-NO0A	COMA-NCA, COMB-NCB, COMC-NOC
0	1	0	1	COM-NO5	COMB-NO1B, COMA-NO1A	COMA-NOA, COMB-NCB, COMC-NOC
0	1	1	0	COM-NO6	COMB-NO2B, COMA-NO2A	COMA-NCA, COMB-NOB, COMC-NOC
0	1	1	1	COM-NO7	COMB-NO3B, COMA-NO3A	COMA-NOA, COMB-NOB, COMC-NOC

X = Don't care

Note: NO and COM pins are identical and interchangeable. Either may be considered an input or output; signals pass equally well in either direction.

_Applications Information Power-Supply Considerations

Overview

The MAX4051/MAX4052/MAX4053 and MAX4051A/MAX4052A/MAX4053A construction is typical of most CMOS analog switches. They have three supply pins: V+, V-, and GND. V+ and V- are used to drive the internal CMOS switches and set the limits of the analog voltage on any switch. Reverse ESD-protection diodes are internally connected between each analog signal pin and both V+ and V-. If any analog signal exceeds V+ or V-, one of these diodes will conduct. During normal operation, these (and other) reverse-biased ESD diodes leak, forming the only current drawn from V+ or V-.

Virtually all the analog leakage current comes from the ESD diodes. Although the ESD diodes on a given signal pin are identical, and therefore fairly well balanced, they are reverse biased differently. Each is biased by either V+ or V- and the analog signal. This means their leakages will vary as the signal varies. The *difference* in the two diode leakages to the V+ and V- pins constitutes the analog signal path leakage current. All analog leakage current flows between each pin and one of the supply terminals, not to the other switch terminal. This is why both sides of a given switch can show leakage currents of either the same or opposite polarity.

There is no connection between the analog signal paths and GND.

^{*} ADDC not present on MAX4052.

V+ and GND power the internal logic and logic-level translators, and set both the input and output logic limits. The logic-level translators convert the logic levels into switched V+ and V- signals to drive the gates of the analog signals. This drive signal is the only connection between the logic supplies (and signals) and the analog supplies. V+ and V- have ESD-protection diodes to GND.

The logic-level thresholds are TTL/CMOS compatible when V+ is +5V. As V+ rises, the threshold increases slightly, so when V+ reaches +12V, the threshold is about 3.1V; above the TTL-guaranteed high-level minimum of 2.8V, but still compatible with CMOS outputs.

Bipolar Supplies

These devices operate with bipolar supplies between $\pm 3.0V$ and $\pm 8V$. The V+ and V- supplies need not be symmetrical, but their sum cannot exceed the absolute maximum rating of $\pm 17V$.

Single Supply

These devices operate from a single supply between +3V and +16V when V- is connected to GND. All of the bipolar precautions must be observed. At room temperature, they actually "work" with a single supply at near or below +1.7V, although as supply voltage decreases, switch on-resistance and switching times become very high.

Overvoltage Protection

Proper power-supply sequencing is recommended for all CMOS devices. Do not exceed the absolute maximum ratings, because stresses beyond the listed ratings can cause permanent damage to the devices. Always sequence V+ on first, then V-, followed by the logic inputs (NO) and by COM. If power-supply sequencing is not possible, add two small signal diodes (D1, D2) in series with the supply pins for overvoltage protection (Figure 1).

Adding diodes reduces the analog signal range to one diode drop below V+ and one diode drop above V-, but does not affect the devices' low switch resistance and low leakage characteristics. Device operation is unchanged, and the difference between V+ and V-should not exceed 17V. These protection diodes are not recommended when using a single supply if signal levels must extend to ground.

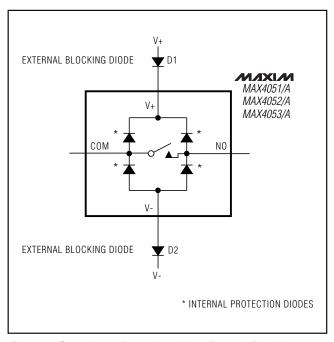


Figure 1. Overvoltage Protection Using External Blocking Diodes

High-Frequency Performance

In 50Ω systems, signal response is reasonably flat up to 50MHz (see *Typical Operating Characteristics*). Above 20MHz, the on response has several minor peaks which are highly layout dependent. The problem is not turning the switch on, but turning it off. The off-state switch acts like a capacitor, and passes higher frequencies with less attenuation. At 10MHz, off isolation is about -45dB in 50Ω systems, becoming worse (approximately 20dB per decade) as frequency increases. Higher circuit impedances also make off isolation worse. Adjacent channel attenuation is about 3dB above that of a bare IC socket, and is entirely due to capacitive coupling.

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Test Circuits/Timing Diagrams

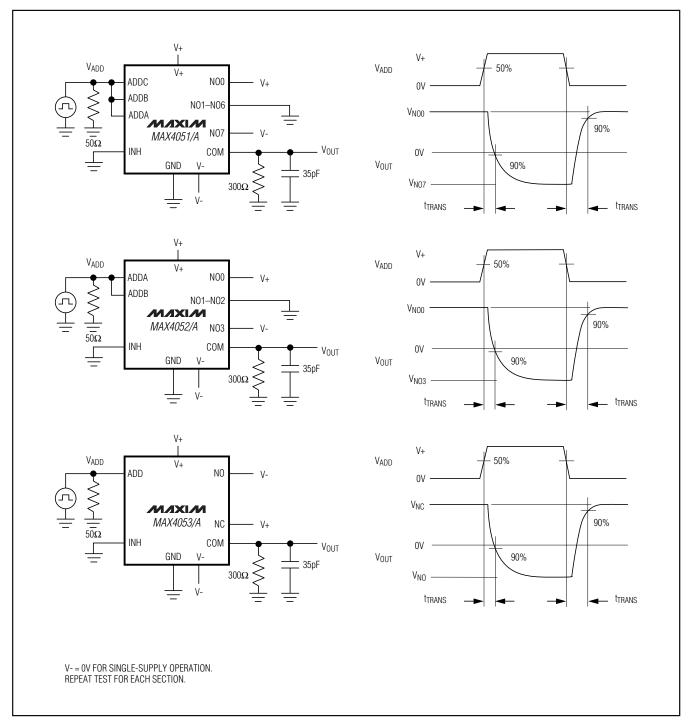


Figure 2. Address Transition Time

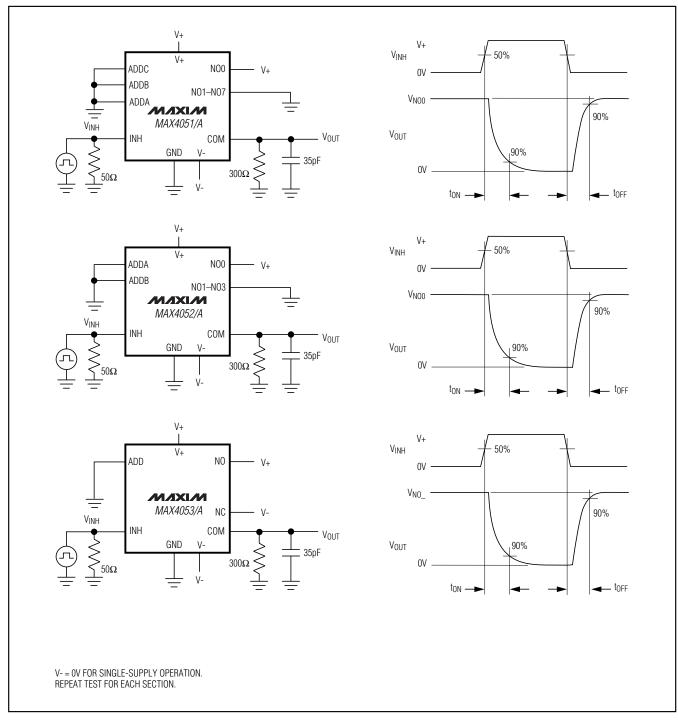


Figure 3. Enable Switching Time

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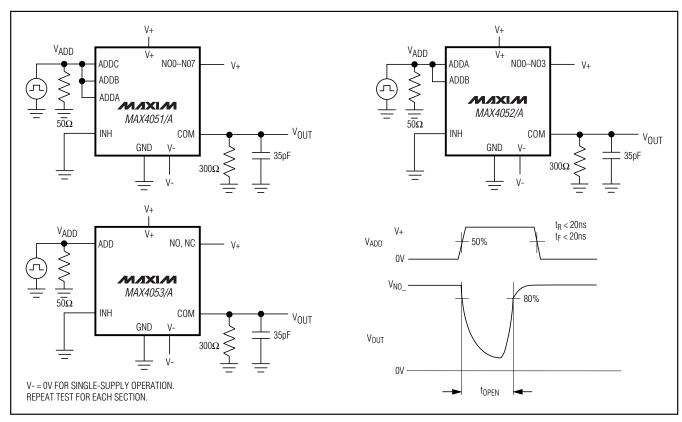


Figure 4. Break-Before-Make Interval

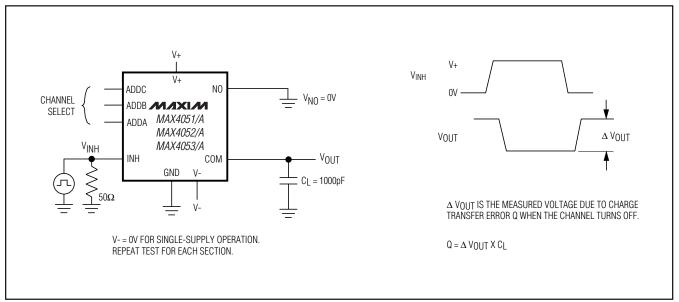


Figure 5. Charge Injection

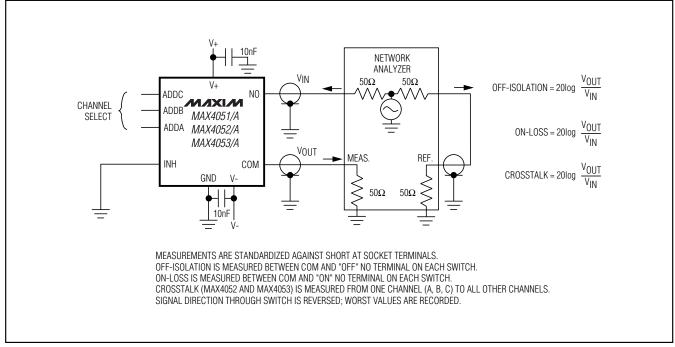


Figure 6. Off-Isolation, On-Loss, and Crosstalk

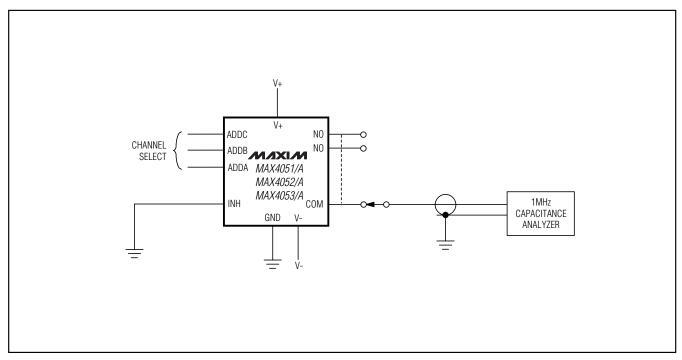


Figure 7. NO/COM Capacitance

Ordering Information (continued)

PART	TEMP RANGE	PIN-PACKAGE
MAX4051AEPE	-40°C to +85°C	16 Plastic DIP
MAX4051AESE	-40°C to +85°C	16 Narrow SO
MAX4051AEEE	-40°C to +85°C	16 QSOP
MAX4051AMJE	-55°C to +125°C	16 CERDIP**
MAX4051CPE	0°C to +70°C	16 Plastic DIP
MAX4051CSE	0°C to +70°C	16 Narrow SO
MAX4051CEE	0°C to +70°C	16 QSOP
MAX4051C/D	0°C to +70°C	Dice*
MAX4051EPE	-40°C to +85°C	16 Plastic DIP
MAX4051ESE	-40°C to +85°C	16 Narrow SO
MAX4051EEE	-40°C to +85°C	16 QSOP
MAX4051MJE	-55°C to +125°C	16 CERDIP**
MAX4052ACPE	0°C to +70°C	16 Plastic DIP
MAX4052ACSE	0°C to +70°C	16 Narrow SO
MAX4052ACEE	0°C to +70°C	16 QSOP
MAX4052AEPE	-40°C to +85°C	16 Plastic DIP
MAX4052AESE	-40°C to +85°C	16 Narrow SO
MAX4052AEEE	-40°C to +85°C	16 QSOP
MAX4052AMJE	-55°C to +125°C	16 CERDIP**
MAX4052CPE	0°C to +70°C	16 Plastic DIP
MAX4052CSE	0°C to +70°C	16 Narrow SO
MAX4052CEE	0°C to +70°C	16 QSOP
MAX4052C/D	0°C to +70°C	Dice*
MAX4052EPE	-40°C to +85°C	16 Plastic DIP
MAX4052ESE	-40°C to +85°C	16 Narrow SO
MAX4052EEE	-40°C to +85°C	16 QSOP
MAX4052MJE	-55°C to +125°C	16 CERDIP**

TEMP RANGE	DIN : D 4 O 1 / 4 O E
I LIVIE NAINGE	PIN-PACKAGE
0°C to +70°C	16 Plastic DIP
0°C to +70°C	16 Narrow SO
0°C to +70°C	16 QSOP
-40°C to +85°C	16 Plastic DIP
-40°C to +85°C	16 Narrow SO
-40°C to +85°C	16 QSOP
-55°C to +125°C	16 CERDIP**
0°C to +70°C	16 Plastic DIP
0°C to +70°C	16 Narrow SO
0°C to +70°C	16 QSOP
0°C to +70°C	Dice*
-40°C to +85°C	16 Plastic DIP
-40°C to +85°C	16 Narrow SO
-40°C to +85°C	16 QSOP
-55°C to +125°C	16 CERDIP**
	0°C to +70°C 0°C to +70°C 0°C to +70°C -40°C to +85°C -40°C to +85°C -40°C to +85°C 0°C to +70°C -40°C to +85°C -40°C to +85°C -40°C to +85°C -40°C to +85°C

^{*} Contact factory for dice specifications.

_Chip Information

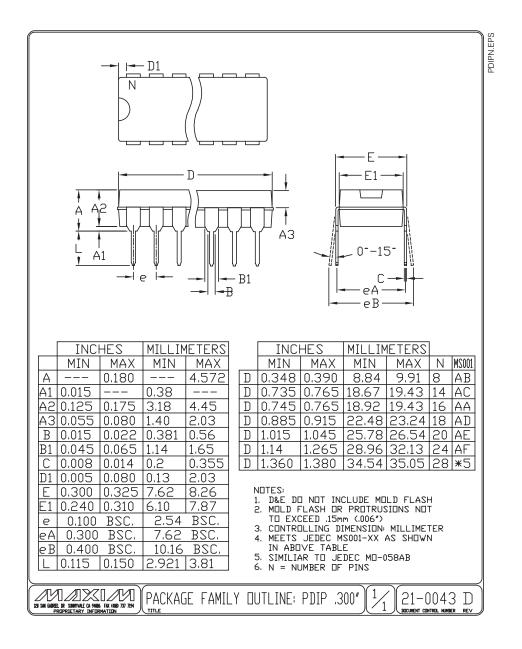
TRANSISTOR COUNT: 161
SUBSTRATE CONNECTED TO V+.

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^{**} Contact factory for availability.

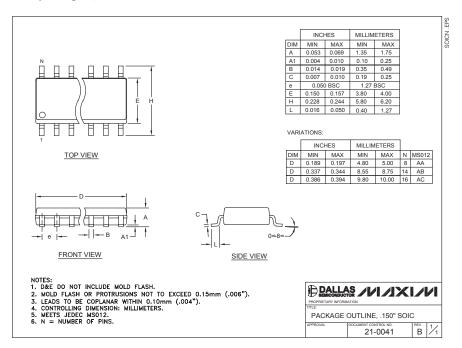
Package Information

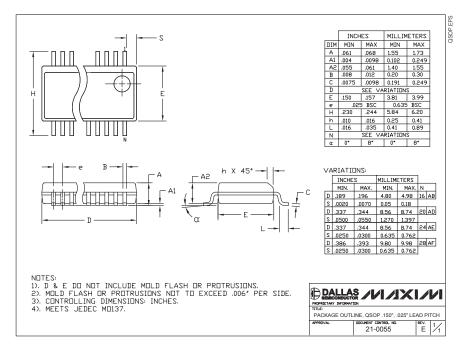
(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)



Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to www.maxim-ic.com/packages.)





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